

L Number	Hits	Search Text	DB	Time stamp
1	46	semiconductor and bidirectional and lateral and (igbt or (insulated adj gate adj bipolar adj transistor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/05/17 13:40

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semiconductor and (igbt or (insulated adj gate adj bipolar adj transistor)) and lateral	30

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L1    semiconductor and (igbt or (insulated adj gate adj bipolar adj transistor)) and lateral

30    L1

END OF SEARCH HISTORY

L Number	Hits	Search Text	DB	Time stamp
1	848	(257/119, 141, 162, 343, 492, "493").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/17 15:17

L Number	Hits	Search Text	DB	Time stamp
1	518	(123/650, 651, "652").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/05/17 16:42